Transition metal dichalcogenide dimer nano-antennas with ultra-small gaps

Panaiot G. Zoteva∗, Yue Wang∗∗, Luca Sortinoa,c, Toby Severs Millardb, Nic Mullina, Donato Conteduca, Mostafa Shagarb, Armando Gencoc, Jamie K. Hobbsb, Thomas F. Kraussb, Alexander I. Tartakovskii∗∗∗

1Department of Physics and Astronomy, University of Sheffield, Sheffield S3 7RH, UK
2Department of Physics, University of York, York, YO10 5DD, UK
3Chair in Hybrid Nanosystems, Nano Institute Munich, Faculty of Physics, Ludwig-Maximilians-Universität, München, 80539, Munich, Germany
4p.zotev@sheffield.ac.uk **yue.wang@york.ac.uk ***a.tartakovskii@sheffield.ac.uk

Transition metal dichalcogenides (TMDs) have emerged as promising materials for nanophotonic resonators due to their large refractive index, low absorption within the visible spectrum and compatibility with a wide variety of substrates. Here we use these properties to fabricate WS2 monomer and dimer nano-antennas in a variety of geometries enabled by the anisotropy in the crystal structure. Using dark field spectroscopy, we reveal multiple Mie resonances, including anapole modes, for which we show polarization-sensitive second harmonic generation in the dimer nano-antennas. We introduce post-fabrication atomic force microscopy repositioning and rotation of dimer nano-antennas, achieving gaps as small as 10±5 nm and opening a host of potential applications. We further studied these structures with numerical simulations yielding electric field intensity enhancements of >103 corresponding to Purcell factors as high as 157 for emitters positioned within the nano-antenna hotspots. Optical trapping simulations of small dimer gaps yield attractive forces of >350 fN for colloidal quantum dots and > 70 fN for protein-like, polystyrene beads. Our findings highlight the advantages of using transition metal dichalcogenides for nano-photons by exploring new applications enabled by their unique properties.

Transition metal dichalcogenides (TMDs) have drawn large scientific and technological interest in the past decade since the discovery of a direct band gap in monolayers due to quantum confinement effects [1], which in conjunction with reduced dielectric screening led to strongly bound excitons [2]. These layered materials found their way to research involving integration with nano-photonic structures such as plasmonic and dielectric cavities to realize both weak and strong coupling [3–7], low-threshold lasing [8], Purcell [9,10] and quantum efficiency enhancement [11] of single photon emitters (SPEs) in WS2 as well as coupling to collective resonances such as in periodic structures [12,13]. In these studies, the use of TMDs was limited to single and few-layer samples focusing on coupling emitted light from the material to resonances and cavity modes in different material systems [14].

Alternatively, the fabrication of a photonic resonator from a layered material similar to TMDs was first achieved in hexagonal boron nitride (hBN). Recent reports utilized electron beam induced as well as reactive ion etching of hBN to fabricate suspended one- and two-dimensional photonic crystal cavities as well as ring resonators, circular bragg gratings and waveguides [15,16]. Moreover, hBN microcavity-like structures have been shown to control the spontaneous emission rate of excitons in MoS2 monolayers [17]. Micro-rotator structures, twisted with atomic force microscopy (AFM), have also been shown to facilitate the control of second harmonic generation (SHG) enhancement in hBN. Photonic resonators fabricated in TMDs, however, have only recently been reported even though these materials offer a number of advantages. The refractive index of WS2 in the visible range (n>4) [18] is higher than that of hBN [19] or other high-index dielectrics traditionally used to fabricate nanophotonic resonators such as gallium phosphide [20] or silicon [21–23]. TMDs also often maintain a sizable transparency window in the visible [24] and offer advantages due to their layered nature such as large optical anisotropy [25] and adhesion to a large variety of substrates owing to their van-der-Waals attractive forces [26]. These properties offer the possibility of producing a highly contrasting refractive index boundary by deposition of TMD crystals onto low refractive index materials such as SiO2 [27] thereby providing a straightforward route to highly confined optical resonances.

Reports on TMD photonic structures have demonstrated strong coupling using WS2 photonic crystals [28], gratings [29], nano-antenna resonators [18] as well as TMD bulk flakes [30]. Waveguiding or quaswaveguiding has also been achieved in monolayer WS2 photonic crystals [31] and bulk TMD flakes [25]. TMD nano-disk Mie resonators have also been fabricated to show second and third harmonic generation enhancement [32] and Raman scattering enhancement [33]. Both of the latter reports employed a non-radiative anapole mode which arises due to destructive interference between a dipole electric and a toroidal mag-
netic mode leading to suppressed far-field scattering and confinement of incident radiation [34]. Numerical studies have also explored the possibility of entire optical circuits in TMDs including rib waveguides, photonic crystal cavities and electro-optic modulators [35]. Further theoretical studies open the possibility for realization of MoS$_2$ nano-resonator modes [36] as well as WS$_2$ nano-antenna metasurface resonances [37] characterized as bound states in continuum.

Photonic elements with ultra-small gaps are highly desirable due to the possibility of strong confinement of electric and magnetic fields, similar to ultra-narrow nano-structures fabricated using the etching anisotropy of WS$_2$ crystallographic axes [38]. As evidenced from tip cavity structures in photonic crystal nano-beam cavities [39] as well as from the use of plasmonic bowtie antennas [40], resonators containing a closely spaced double-vertex structure can confine electric fields to far below the wavelength of light due to the boundary conditions on the normal and parallel components of the electric field at a sharp refractive index contrasting boundary [39]. The confined field intensity increases as the separation between high refractive index vertices is reduced [39]. Therefore, very small, low-index gaps yield very large field intensities which can be advantageous for Purcell enhancement of SPEs. The highly confined electric fields in high-index resonators with ultra-small gaps are a prerequisite for large local densities of optical states, which from Fermi’s Golden rule, lead to high radiative emission rates of quantum emitters [41].

An application which would also greatly benefit from the large electric field intensities in such small separations and could aid in the precise positioning of SPEs is optical trapping of nano-particles. These experience an attractive force in the direction of an electromagnetic hotspot under optical excitation. The force is dependent on the particle size, refractive index, the input pump power and the energy confinement provided by the photonic environment [42]. Previous reports of nano-antenna optical trapping utilize plasmonic resonators which have been shown to apply large forces to nano-particles [43], however, they suffer from large changes in temperature leading to loss in stability as well as quenching of emission due to increased optical absorption processes [23, 44]. Alternatively, dielectric nano-resonators, such as silicon dimer nano-antennas [23, 45], can be advantageous for optical trapping in different applications including biological nano-particles at risk of degrading due to heating effects as well as quantum dot positioning without emission quenching.

The smallest achievable lateral, low refractive index gap between two vertex-shaped plasmonic structures has, to the best of our knowledge, only been reported for gold nanotriangles (5 nm) manipulated with an AFM tip [46]. For high-index dielectric structures, the limit is set by focused ion beam (FIB) milling which results in gaps on the order of 10 nm [47] yet it is an irreversible process and damages the crystal, therefore disadvantageous for some applications.

In this work, we pattern nano-antenna structures into thin WS$_2$ crystals. We exfoliate 25 nm - 500 nm thick flakes of WS$_2$ onto a SiO$_2$ substrate and utilize established nano-fabrication techniques such as electron beam lithography (EBL) and reactive ion etching (RIE) to define nanometer-scale antennas. We observe that WS$_2$ can be selectively fabricated in circular, square or novel hexagonal geometries with potentially atomically sharp edges and vertices depending on the etching recipe used. Dark field spectroscopy of single (monomer) and double (dimer) nano-pillar resonators reveals geometric Mie resonances which we compare with finite-difference time-domain (FDTD) simulations. We perform SHG experiments on fabricated structures and reveal polarization dependent enhancement of the signal through coupling to a dimer anapole mode. Subsequently, we utilize contact mode atomic force microscopy (AFM) as a post-fabrication step to reposition the constituent nano-pillars of dimer nano-antennas achieving gaps of 10±5 nm. This also introduces a route to modulate the photonic environment in the dimer gap through separation distance as well as relative rotation of the nano-pillar vertices. We further numerically study the viability of utilizing dimer nano-antennas for photonic enhancement of single photon emitters. We simulate the electric field confinement as well as the Purcell factor for an SPE positioned at the hotspots of the dimer nano-antenna mode. These simulations yield electric field intensity enhancement of >10$^4$ compared to vacuum and Purcell factors of >150 for the hexagonal and square geometries. We further explore different pathways to modulate the enhancement of SPEs in the dimer hotspots using separation of nano-pillars as well as relative rotation, which is intrinsic to the novel hexagonal and square structures. We subsequently numerically explore the prospect of using WS$_2$ dimer nano-antennas with ultra-small gaps in optical trapping. For the smallest experimentally achieved dimer gap, we calculate attractive forces towards the electric field hotspots of >350 fN for colloidal quantum dots (QDs) and >70 fN for polystyrene beads (PBs) which closely emulate large proteins. Our experimental and numerical studies of TMD material photonic resonators opens possibilities for novel research and applications.

Results

Fabrication of nano-antennas WS$_2$ consists of covalently bonded monolayers (Fig. 1(a)) with a hexagonal crystal structure and a thickness of 0.7 nm. These layers are held together by van-der-Waals forces in bulk crystals. We mechanically exfoliated WS$_2$ flakes onto a
290 nm SiO$_2$ on silicon substrate with thicknesses ranging from 25 to 500 nm. Fig. 1(b) shows a schematic representation of the fabrication process. We spun a positive resist onto the sample and patterned circular disks and squares with varying radii using EBL. After development, we transferred the pattern into the WS$_2$ crystals with RIE using two different recipes completed once the etch depth matched the thickness of the exfoliated crystal, defining the nano-antenna height. An anisotropic etch using a mixture of CHF$_3$ and SF$_6$ gases along with a high DC bias and low chamber pressure yielded circular nano-pillars with vertical sidewalls which resulted from the physical etching of the resist pattern into the WS$_2$. Examples of the structure are shown in the AFM and scanning electron microscopy (SEM) images in the upper row of Fig. 1(c).

Upon substitution of the CHF$_3$ with additional SF$_6$ gas, a reduction of the DC bias and an increase in the chamber pressure, the resulting nano-antennas exhibited a hexagonal geometry with a radius defined from the center of the structure to one of the vertices at the edge, as shown in the middle right panel of Fig. 1(b). This radial definition corresponds to the radius of the previously circular resist pattern. The physical etching mechanism was suppressed and the increased proportion of reactive fluorine radicals ensured a dominant chemical etch which preferentially removed the WS$_2$ crystal in the armchair crystal axis leading to zigzag terminated sidewalls at 120$^\circ$ angles to each other following the crystal symmetry. This agrees with DFT results which also predict that zigzag edges are more stable [48,49]. The AFM and SEM images in the middle row of Fig. 1(c) display an example of hexagonal nano-antennas.

The final geometry we achieved was that of a square which resulted from a combination of resist patterning and chemical etching of the WS$_2$. We defined a square resist pattern with sides oriented parallel to the zigzag axis of the crystal. The subsequent chemical etching similarly removed the WS$_2$ in the armchair crystal axes ultimately leading to 90$^\circ$ angles describing a square shaped nano-antenna, examples of which are displayed in the lower panels of Fig. 1(c). The hexagonal geometry and, in part, the square nano-antenna geometry are formed due to the relative stability of the zigzag axis and can therefore lead to atomically sharp vertices.

**Photonic resonances of WS$_2$ nano-antennas** We studied the fabricated structures using dark field spectroscopy and compared the experimental results to FDTD simulations which yielded close agreement (see methods and Supplementary Note 1). We identified an electric dipole resonance with small contributions from higher order modes as well as anapole and higher order anapole modes (HOAM). As expected from Mie theory, the resonances forming in the studied nano-antennas red-shifted with increasing radius and blue-shifted with decreasing height. The ability to change the geometry of nano-antennas through a choice of etching recipe provides an additional, more precise tuning mechanism for the observed resonances (see Supplementary Note 2).

Next we considered more complex architectures by placing a pair of the novel hexagonal nano-pillars in close proximity to form a dimer nano-antenna shown schematically in the left panel of Fig. 2(a). An SEM image of a fabricated structure is also displayed in the right panel of Fig 2(a). When two single nano-pillars are placed in close proximity, their photonic resonances hybridize forming two cross-polarized modes with an energy splitting (see Supplementary Note 3). One of these modes is excited with polarization parallel to the axis connecting the midpoints of the single nano-pillars (dimer axis), which we name the X-pol mode, while the other is excited perpendicularly, here named the Y-pol mode.

We recorded dark field spectra for dimer nano-antenna structures with a height of $h = 60$ nm and compared these to simulations. Fig. 2(b) shows this comparison for unpolarized excitation at three different radii (165 nm, 185 nm and 200 nm) and a dimer gap of $g = 130$ nm yielding close agreement. Dark field scattering spectra for the X-pol and the Y-pol modes can be found in Supplementary Note 4 showing the hybridization of the anapole resonance. Moreover, we measured a larger set of nano-antennas with a similar height (60 nm) spanning a range of radii from 165 nm to 220 nm which can be found in Supplementary Note 5. This study also revealed a red-shift of all resonances with increasing radius confirming their geometric origins and asserting the tuning mechanism for the dimer nano-antenna modes to be the same as for the monomer.

The dashed, red lines in Fig. 2(b) represent the normalized, confined electric energy inside the structure, simulated for a surface at the midpoint of the nano-antenna height. Similar to the behavior seen in the monomer nano-antennas, we recorded a minimum in the scattering spectra of the dimer nano-antennas at long wavelengths (800 nm for $r = 200$ nm) coinciding with a maximum in the simulated, confined electric energy. This correlation, together with the electric and magnetic field intensity pattern at this wavelength, shown in Fig. 2(c), are all characteristic of a dimer anapole mode [34]. When compared to the same resonance in monomers, the dimer anapole mode yields a more tightly confined electric energy (see Supplementary Note 6).

**Second harmonic generation enhancement** We recorded second harmonic generation spectra from a dimer ($r = 205$ nm, $h = 60$ nm, $g = 130$ nm) and monomer nano-antenna ($r = 215$ nm, $h = 50$ nm),
which both host anapole modes near 800 nm, as well as
from a bulk crystal (h = 60 nm) using a 804 nm pulsed
Ti-sapphire laser excitation linearly polarized perpen-
dicular to the dimer axis (Y-pol). Fig. 2(d) displays
the SHG spectra normalized to the excited area. For
the bulk measurement, the intensity was normalized to
the area of the laser spot size (A = πr² for r = 700 nm).
The hexagonal nano-antenna measurements were nor-
malized to their respective areas (A_{nano} = 3r²√3/2
for the monomer with r = 215 nm and A_{di} = 3r²√3
for the dimer with r = 205 nm). We extracted an SHG
enhancement factor by integrating the normalized sec-
ond harmonic signal at the dimer nano-antenna posi-
tion (yellow in Fig. 2(d)) and dividing by a the simi-
larly integrated signal from the bulk flake (purple dots),
yielding a factor of 7.2. The recorded signal from the
monomer was comparable to the dimer nano-antenna
which is expected from simulations of the electric en-
ergy stored in the anapole mode (see Supplementary
Note 6).

We further studied the polarization dependence of
the nano-antennas by shifting the excitation laser to
850 nm, rotating its linear polarization and collect-
ing integrated second harmonic signal through the use
of an avalanche photo-diode (APD). The laser wave-
length used for these experiments was chosen due to
the larger difference of confined electric energy ex-
pected for the X-pol and Y-pol modes of the dimer.
The normalized polarization dependent SHG intensity
was recorded for a dimer (r = 200 nm, h = 60 nm,
g = 130 nm), monomer (r = 240, h = 50 nm) and
bulk as shown in Fig. 2(e). Upon comparison of the
measured signals, we observed a clear polarization of
the second harmonic signal for the dimer nano-antenna
while the same is not evident for the bulk or monomer
nano-antenna measurements. As the excitation po-
arization is rotated, the X-pol and subsequently the
Y-pol modes confine incident light differently leading
to the observed polarization dependence. The electric
field is mainly confined to the outside edges of the
nano-antenna for the X-pol anapole mode, thereby not
contributing to the SHG enhancement. For the Y-pol
mode, however, the confinement is mostly inside the
nano-antenna structure. The position of the confined
electric field in the monomer and bulk does not change,
therefore, leading to no polarization dependence of the
SHG enhancement. We compare the experimental data
to simulations of the relative SHG signal (possible due
to its dependence on the electric energy squared [20])
and observed good agreement between simulation and
experiment for both structures shown in Fig. 2(e).

**AFM repositioning** The fabrication procedure out-
lined in Fig. 1 yields minimum dimer separation gaps
of 50 nm, therefore, we attempted to improve upon
this by using the properties of layered materials to our
advantage. The relatively weak van-der-Waals forces
which facilitate mechanical exfoliation of thin WS₂
2 crystals also allow for a weak adhesion of the fabri-
cated structures to the SiO₂/Si substrate. As a post-
fabrication procedure, we employed an AFM cantilever
in order to translate one nano-pillar with respect to
the other and achieve gaps as small as 10 nm without
damaging the nano-antenna. Smaller separation distances
may be achievable, however, the accurate measurement
of the gap width is a considerable challenge due to the
finite size of the AFM tip which is <5 nm.

The method of repositioning used a contact mode
AFM cantilever which scanned parallel to the dimer
axis on the outside edge of a dimer nano-antenna.
Choosing a low set-point in order to position the can-
tilever close to the sample surface forced it to collide
with the nano-antenna during each sweep and displace
it. A schematic representation of the translation can
be seen in Fig. 3(a). Very fine positioning can be
achieved using this method as shown in Fig. 3(b) where
we translated one nano-pillar with respect to other re-
ducing the dimer gap separation from 105 nm to 15±5
nm.

An additional advantage of using this repositioning
method is the ability to rotate the nano-pillars with
great precision (<1°). As shown in the bottom panel
of Fig 3(b), by scanning the AFM cantilever along a
tangent of one of the nano-pillars colliding with only
the edge, it was rotated by over 8⁰ as well as translated
closer to the other nano-pillar allowing fine position-
ing of the inside vertices of the dimer. Further atomic
force microscopy scans of repositioned nano-antennas
are displayed in Supplementary Note 7 confirming the
reproducibility of the procedure and showing the min-
imum gap separation we have achieved (10±5 nm).

To confirm that the photonic response was mod-
ified by the AFM repositioning, we performed dark
field spectroscopy before and after the translation pro-
cedure. As shown in Fig. 3(c), the dipolar resonance
seen in scattering increased for an excitation parallel to
the dimer axis, which is the most sensitive configura-
tion to changes in gap separation. The dashed lines in
the same figure represent simulations of the geometry
before and after repositioning with close agreement to
experiment confirming the achieved 15 nm gap.

**Electric field and Purcell enhancement of emis-
ion** Ultra-small gaps, such as those achieved with the
AFM repositioning technique are expected to provide
very high electric field confinements [39]. We there-
fore simulated the electric field intensity and Purcell
enhancement induced by three dimer designs, corre-
sponding to the different geometries shown in Fig. 1,
with a gap of 10 nm. Each design was optimized for
electric field confinement at the top surface of the
dimer.

We have simulated the electric field intensity spa-
tial distribution 0.5 nm above the top surface of the
dimers, shown in the left column of Fig. 4(a), as well as a cross sectional cut along the z-axis through the middle of the individual nano-pillars, shown in the right column of Fig. 4(a). Each distribution was calculated at the wavelength of the maximum electric field intensity (751.5 nm, 749.5 nm, 697.5 nm for the circular, hexagonal and square geometries respectively). The radii of the optimized geometries are $r = 225$ nm, $r = 240$ nm and $r = 260$ nm for the circular, hexagonal and square geometries respectively, while their heights are $h = 200$ nm, $h = 200$ nm and $h = 150$ nm. In order to closely approximate realistic structures which can be fabricated, we measured the radius of curvature of the vertices of fabricated hexagonal and square dimer nano-antennas using atomic force microscopy. This yielded vertex radii of curvature as low as 22 nm for the hexagonal and 10 nm for the square geometry (see Supplementary Note 8). These values were then subsequently taken into account in the simulation of the hexagonal and square geometries. The electric field hotspots forming at the vertices between the two nano-pillars for an incident plane wave polarized parallel to the dimer axis exhibit intensities of more than $10^6$ compared to vacuum as shown in Fig. 4(a). We compare the hotspots simulated for the three geometries achievable through the fabrication process. The hexagonal and square shaped nano-antennas induce a higher electric field intensity confinement than the circular design, with the hexagonal geometry inducing the largest enhancement.

Furthermore, we evaluated the Purcell factor for a single photon source positioned onto these structures by simulating a dipole emitter at positions along the dimer axis with a polarization parallel to the same axis. It is displaced by 0.5 nm from the top surface of the structure and its emission wavelength was set to the one used for Fig. 4(a). The calculated Purcell factors at each position are shown in Fig. 4(b). Solid white lines in the left panels of Fig. 4(a) indicate the simulated positions of the emitter. The maxima seen at positions corresponding to the inner edges of the nano-antenna yield the largest results (>100) as expected from the electric field hotspots seen in Fig.4(a). Weakly confined hotspots at the outside edges of the structure also exhibit local maxima in the Purcell factor with values as high as 20. For the minimum achieved gap separation in the post-fabrication AFM repositioning, the hexagonal geometry exhibits the highest Purcell factor within its hotspot (157) with the square as a close second (153). The circularly shaped dimer leads to a maximal Purcell factor of 105. We have also simulated the Purcell factors for the minimum gap separation achievable without the use of AFM repositioning (50 nm), which are shown in Fig. 4(b) as dashed lines. This yields much smaller Purcell enhancements (as high as 46).

There are several degrees of freedom in the fabrication process as well as the AFM repositioning which can be used to control the magnitude of the enhancement of single photon emission within these hotspots. One approach involves the separation of the two nano-pillars in the dimer. We numerically studied the effect of moving the two nano-pillars apart from each other (schematically depicted in Fig. 4(c)) on the electric field intensity and Purcell factor at the hotspots in Fig. 4(d) and (e). We also compared these effects for the three dimer designs. Both the electric field intensity and Purcell factor decrease exponentially with separation distance. The hexagonal structure yields the highest electric field confinement at small separations, however the intensity induced by the square structure is highest for large gap values (>75 nm). The Purcell factor of the square structure, however, exceeds that of the hexagonal at separation values as low as 20 nm.

Another approach available only to the hexagonal and square nano-antennas takes into account the control of the alignment of the two nano-pillars relative to each other. One method to achieve such alignment was previously shown in Fig. 3 through AFM positioning, while another method utilizes the chemical etching mechanism which etches faster in the armchair axis of the crystal. Therefore, two nano-pillars fabricated spatially close to each other will always have the same orientation with respect to the symmetry of the original crystal. However, if the dimer nano-antenna design is rotated at the electron beam patterning stage of the fabrication procedure, as displayed in Fig.4(f), the relative orientation of the antennas will have changed along the new axis connecting their centers, thereby, positioning their vertices closer or further apart from each other. As shown in Fig.4(g) and (h), this can lead to a more subtle modulation of the the electric field intensity and the Purcell enhancement for a quantum emitter located within the hotspots. The range of angles available to the hexagonal geometry is limited to 30°, while the square structure can be rotated to 45° before the electric field intensity and Purcell factor begin to increase once more.

**Dimer nano-antenna optical trapping** In order to study the potential of ultra-small gap WS$_2$ dimer nano-antennas for optical trapping, we perform numerical simulations based on the Finite Element Method (FEM) to determine the Maxwell Stress Tensor (MST) and calculate the force exerted on small dielectric particles. The simulation geometry consists of the earlier optimized hexagonal nano-antenna with the addition of a nano-sphere (r = 5 nm) with a refractive index corresponding to either an approximated colloidal quantum dot (n = 2.4) [45] or a polystyrene bead (n = 1.6), which closely mimics the refractive index and size of a large protein [50]. Since optical trapping experiments often require a suspension of the nano-particles in a solution, we set the background refractive index to that
of water. For all simulations, we use an experimentally feasible pump power density of 10 mW/µm². A schematic representation of the simulation is shown in Fig. 5(a).

We explore the optical force applied to the QD and the PB, as shown Fig. 5(b) and (c) respectively, as they are translated along the z-axis in the middle of the dimer gap. We simulate the forces for two gap separations of the dimer hexagonal nano-antenna (10 nm and 15 nm) and observe an attractive (negative) force which is maximized at the top surface of the nano-antenna where the electric field hotspots are formed. We observe a maximum optical force of 353 fN on the QD and 73 fN on the PB for the dimer nano-antennas with a 10 nm separation. For the larger dimer gap (15 nm), this reduces to 123 fN on the QD and 31 fN on the PB. We also study the dependence of this maximum optical force in the electric field hotspots on the dimer gap, which is varied from 10 nm to 50 nm. As shown in Fig. 5(d), the maximum attractive force imparted on the nano-particles decreases exponentially by one order of magnitude as expected from the decay of the electric field intensity with an increased separation, shown in Fig. 4(d). We subsequently explore the spatial dependence of the optical force by simulating the QD and PB in a plane which is 5 nm above the top surface of the dimer nano-antenna with a 10 nm gap, as shown in Fig. 5(e) and (f). This is an emulation of the position of nano-particles placed onto the top surface of the dimer. The optical force, as expected, is maximized at the position of the electric field hotspots but also polarization dependent SHG, not present in harmonic generation from a nanometer-scale structure. As shown in Fig. 5(d), the maximum attractive force which is maximized at the top surface of the nano-antenna is higher than the largest currently achieved in photonic crystal cavities due to the previously inaccessibly small proximity attained with the AFM repositioning method. We also discuss two different routes to modulate the photonic enhancement through variation of the dimer gap as well as the relative rotation of the individual nano-pillars which are both controllable through either the fabrication process or, to a greater precision, the post-fabrication repositioning. These methods of controlling the emission properties of single photon sources may prove useful for WS₂ SPEs which form at high strain gradients in monolayers transferred onto dimer nano-antennas COLLOCATED with the electric field hotspots [53].

Discussion

We have fabricated and characterized both monomer and dimer WS₂ nano-antennas with the aim to highlight the advantages of their use in photonic applications such as polarization dependent SHG enhancement, SPE enhancement and optical trapping thereby broadening the versatility of TMD nano-antennas. Dark field studies on monomer and dimer nano-antennas reveal a straightforward approach for tuning resonances inside the nano-antennas in order to fit with different applications by varying the radius, height or geometry. Through the use of a dimer anapole mode, we not only show enhanced second harmonic generation from a nanometer-scale structure but also polarization dependent SHG, not present in bulk TMD flakes or monomer nano-antennas. Post-fabrication repositioning of dimer nano-antennas utilizing AFM led us to attain ultra-small gaps of 10±5 nm, on the order of the feature resolution limit set by FIB milling [47], which we achieve through a more precise, less damaging and reversible technique. Although a previous report has demonstrated AFM positioning of plasmonic bowtie nano-antennas [46], this technique has only become possible for dielectric nano-antennas made from layered materials due to their intrinsic van-der-Waals attractive forces. This allows us to change the separation of individual nano-pillars, thereby, aligning their potentially atomically sharp vertices in closer or further proximity.

The numerical simulation studies of dimer nano-antennas exhibiting an ultra-small gap yield highly confined electric field intensity hotspots (10³ enhancement compared to vacuum). We predict the practical utility of WS₂ nano-antennas for radiative rate enhancement of single photon emission with Purcell factors of up to 157 for a hexagonal and 153 for a square geometry. The expected quantum emission enhancement in the dimer nano-antennas is higher than the largest currently achieved in photonic crystal cavities due to the previously inaccessibly small proximity attained with the AFM repositioning method. We also discuss two different routes to modulate the photonic enhancement through variation of the dimer gap as well as the relative rotation of the individual nano-pillars which are both controllable through either the fabrication process or, to a greater precision, the post-fabrication repositioning. These methods of controlling the emission properties of single photon sources may prove useful for WS₂ SPEs which form at high strain gradients in monolayers transferred onto dimer nano-antennas colloced with the electric field hotspots [53]. Previous reports have shown quantum efficiency enhancement for WS₂ SPEs [11] as well as rotation of the emitter dipole moment due to a change in the strain gradient [54] both of which can be controlled through a decrease in separation and a rotation of individual nano-pillars in the dimer nano-antenna through AFM repositioning.

We further explored a route to the precise positioning of SPEs by simulating optical trapping forces due to the highly confined electric field in the gap of the dimer nano-antennas. We calculated a maximum attractive force of 353 fN for a colloidal quantum dot and 73 fN for a protein-like, polystyrene bead both with a radius of 5 nm under a pump power density of 10 mW/µm². When compared to previous examples of dielectric nano-antennas for optical trapping, the WS₂ dimers yield higher attractive forces by a factor of >83 for QDs [45] and >40 for PBs [23] with the same size and under the same pump power conditions. Therefore, WS₂ dimer nano-antennas with ultra-small gaps show great potential for applications of stable trapping of very small nano-particles with a moderate optical power, once again highlighting the advantage of the AFM repositioning technique to reduce
the dimer gap below the limits available to standard nano-fabrication. The large Purcell enhancements and optical trapping forces predicted for WS\(_2\) dimer nano-antennas with ultra-small gaps highlight the unique potential for TMD nano-resonator research and applications. This is possible due to the refractive index and van-der-Waals forces which allow the formation of highly confined resonances and hotspots while simultaneously opening the possibility of AFM repositioning. The field of nano-photonics includes a diverse library of materials and here we assert and expand the possibilities provided by adding thin crystals of TMDs to the list.

**Methods**

**Sample fabrication**

**Exfoliation:** WS\(_2\) flakes were mechanically exfoliated from bulk crystal (HQ-graphene) onto a nominally 290 nm SiO\(_2\) on silicon substrate. Large flakes with recognizable crystal axes via straight edged sides at 120° to each other were identified and their positions within the sample were recorded for further patterning.

**Electron beam lithography:** Samples were spin coated with ARP-9 resist (AllResist GmbH) at 3500 rpm for 60 s and baked at 180° for 5 min yielding a film of 200 nm thickness. Electron beam lithography was performed in a Raith GmbH Voyager system operating at 50 kV using a beam current of 560 pA.

**Reactive ion etching** Anisotropic etching to imprint the resist pattern into the WS\(_2\) flakes physically was carried out using a mixture of CHF\(_3\) (14.5 sccm) and SF\(_6\) (12.5 sccm) at a DC bias of 180 V and a pressure of 0.039 mbar for 40 seconds. Isotropic etching was achieved by using a more chemical recipe with solely SF\(_6\) (20 sccm) at a DC bias of 50 V and a pressure of 0.13 mbar for 40 seconds. Removal of the remaining resist after etching was accomplished by a bath in warm 1165 resist remover (1 hour) followed by Acetone (5 min) and IPA (5 min). If resist is still found on the sample, final cleaning is done in a bath of Acetone (1 hour) and IPA (5 min) followed by 1 hour in a UV ozone treatment.

**Dark field spectroscopy** Optical spectroscopy in a dark field configuration was achieved using a Nikon LV150N microscope with a fiber-coupled output. Incident illumination from a tungsten halogen lamp in the microscope was guided to a circular beam block with a diameter smaller than the beam diameter. The light was then reflected by a 50:50 beam-splitter towards a 50x Nikon (0.8 NA) dark-field objective which only illuminates the sample at large angles to the normal. Reflected light from the sample is guided back through the same objective towards a fiber coupler. Due to the small diameter of the multi-mode fiber core used, only light reflected back at small angles to the normal is collected. The fiber from the microscope was subsequently coupled to a Princeton Instruments spectrometer and charge coupled device (CCD).

**Second Harmonic Generation** In order to probe the second harmonic generated signal from the nano-antennas, we used a home-built setup with a Spectra-Physics Ti-sapphire mode-locked fs laser as the excitation source. The collimated laser light passed through a linear film polarizer, dichroic mirror and half wave plate was incident on a 100x (0.7 NA) Mitutoyo objective which focused the excitation light onto the sample allowing us to probe single nano-antennas. Second harmonic generated light was then collected using the same objective subsequently passing the light through the half wave plate and reflecting it from the dichroic mirror. The collected light is then filtered by 3 long-pass filters (450, 550, 750 nm cutoff) and coupled to a multi-mode fiber and sent to a Princeton Instruments spectrometer and CCD (data displayed in Fig. 2(d)) or an ID Quantique avalanche photo-diode (id100) (data displayed in Fig. 2(e)). The incident illumination used for Fig. 2(d) (Fig. 2(e)) was set to 804 nm (850 nm) with 1 mW (3 mW) average power. In order to confirm that we measured second harmonic signal using the APD with minimal background noise, we first confirmed the spectral response of the signal from a bulk flake on the CCD.

**Atomic force microscope repositioning and imaging** All repositioning was carried out using a JPK Nanowizard 3 Ultra AFM using Bruker SNL probes (cantilever C, nominal stiffness 0.24 N/m). First, nano-antennas were imaged in QI mode with a setpoint of 1 nN, a Z length of 400 nm and a pixel time of 15 ms. To reposition the antennas, the AFM was switched to contact mode and 200 nm scans were performed with a setpoint of 1 nN and a scan rate of 2 Hz on the substrate immediately adjacent to the antenna. The fast scan axis was oriented along the desired direction of movement and the scan area was progressively moved so that the scan overlapped with the antenna to translate it in the desired direction in increments of 5-50 nm at a time. Periodically, the antenna was re-imaged in QI mode to check the relative position and orientation of the pillars. Final characterization after repositioning was performed in QI mode.

**FDTD simulations** The finite-difference time-domain simulations were carried out using Lumerical Inc. software.

**Scattering simulations:** Calculations of the scattering cross section shown in Figs. 2 and 3 were carried out by defining the geometry of the WS\(_2\) nano-antennas onto a SiO\(_2\) substrate utilizing the refractive index of WS\(_2\) from Reference [18]. Illumination with a plane wave was sent normal to the surface using a
TFSF source from the air side. For Fig. 2 the illumination was unpolarized, however, for Fig. 3 the polarization was set parallel to the dimer axis. The scattered intensity was subsequently collected from a monitor set above the illumination plane (in the far-field) so that the dark field spectroscopy experiments could be closely emulated.

**Electric field intensity simulations**: Calculations of the near-field electric field intensity normalized to vacuum, shown in Fig. 4(a), (d) and (g) were simulated using the same geometry and illumination scheme as for the scattering simulations (polarization is shown as a white double arrow in top left corner of each panel) with a monitor recording the electric field 0.5 nm above the top surface of the nano-antennas or as a vertical cross-section of the structure passing through the dimer axis as shown in the right-most panels of Fig. 4(a). For Fig. 2(c), the monitor was designed as a cross-sectional profile through the midpoint of the nano-antenna height. For Figs. 2(c) and 4(a) this monitor was defined to encompass the entire cross section of the nano-antennas. For Figs. 4(d) and (g) only a single point 1 nm from the inside edge of the dimer nano-antenna within the hotspot was recorded.

**Electric energy simulations**: Calculations of the confined electric energy inside dimer nano-antennas shown in Fig. 2(b) was performed according to equation 1 in Supplementary Note 6. The spatial distribution of the electric field intensity was first simulated for a cross-sectional cut through the midpoint of the nano-antenna height for a range of wavelengths. Subsequently, the integration of the intensities was carried out over the cross-sectional surface only for positions inside the nano-antenna structure. In order to simulate the relative, integrated polarization dependent SHG signal in Fig. 2(e), we performed the same electric energy calculation as for Fig. 2(b) over a range of polarization angles for the dimer and monomer structures and squared the results obtained [20]. For each polarization angle, we integrated the squared electric energy over the laser spectrum in order to be able to compare the simulation to experiment.

**Purcell factor simulations**: Simulations of the Purcell factor were carried out using the same geometry as for the electric field intensity simulations. The illumination was achieved through a dipole source placed at positions along the dimer axis 0.5 nm above the top surface of the nano-antenna with a polarization parallel to the dimer axis for Fig. 4(h). For Figs. 4(e) and (h) however, the position was set to 0.5 nm above the top surface of the nano-antenna and 1 nm away from the inside edge within the electric field hotspot. The polarization of the dipole in Fig. 4(e) and (h) was kept the same as in Fig. 4(b).

**Optical trapping force simulations**: We have used the 3D finite element method (COMSOL Multiphysics) to calculate the optical forces in the hexagonal dimer nano-antenna. The structure is illuminated with a plane wave propagating in a normal direction to the top surface of the structure with a polarization along the dimer axis. The background refractive index was set to that of water to enable access of the bead to the trapping site. We have calculated the optical forces at the resonance of the nano-antenna, corresponding to the maximum energy enhancement. The value of the optical force is obtained by integrating the Maxwell Stress Tensor on the surface of the target nano-particle [42]. A fine mesh (resolution of ≤ 3 nm) has been employed in the dimer gap to calculate the electromagnetic distribution with a high accuracy, minimizing the error on the evaluation of the optical force. The computational domain has been set to a sufficiently large value (>2 µm) and surrounded by perfectly matched layers in order to avoid undesired reflection and scattering from the boundary.

### Acknowledgments

P. G. Z., L. S., T.S.M., M.S., A. G. and A. I. T. thank the financial support of the European Graphene Flagship Project under grant agreements 881603 and EPSRC grants EP/S030751/1, EP/V006975/1 and EP/P026850/1. L. S. and A. I. T. thank the European Union’s Horizon 2020 research and innovation programme under ITN Spin-NANO Marie Sklodowska-Curie grant agreement no. 676108. P. G. Z. and A. I. T. thank the European Union’s Horizon 2020 research and innovation programme under ITN 4PHOTON Marie Sklodowska-Curie grant agreement no. 721394. T.F.K. acknowledges the support of the Engineering and Physical Sciences Research Council (grant number EP/P030017/1). Y.W. acknowledges a Research Fellowship (TOAST) awarded by the Royal Academy of Engineering.

### Author contributions

P.G.Z and L.S. exfoliated WS$_2$ layers onto SiO$_2$ substrates. Y.W. fabricated nano-antenna structures using EBL and RIE. P.G.Z and Y.W. performed AFM and SEM characterization of fabricated nano-antennas. P.G.Z. carried out dark field spectroscopy measurements, scattering cross section simulations and electric/magnetic field intensity profile simulations for identification of WS$_2$ nano-antenna resonances. P.G.Z., T.S.M. and A.G. performed second harmonic generation experiments on WS$_2$ nano-antennas. N.M. repositioned dimer nano-antennas using AFM. P.G.Z. and M.S., simulated electric field intensity profiles and Purcell factors for optimized dimer nano-antennas as well as for studies on dimer gap separation and rotation. D.C. performed optical trapping simulations and analyzed the results with Y.W., T.F.K. P.G.Z.,
L.S., T.S.M. and A.I.T. analyzed various optical spectroscopy data. J.H., T.F.K., Y.W. and A.I.T. managed various aspects of the project. P.G.Z. and A.I.T. wrote the manuscript with contributions from all co-authors. P.G.Z., L.S., Y.W., N.M., D.C., J.H., A.I.T. and T.F.K. conceived the experiments and simulations. A.I.T. oversaw the entire project.

**References**


[17] H. H. Fang, B. Han, C. Robert, M. A. Semina, D. Lagarde, E. Courtade, T. Taniguchi, K. Watanabe, T. Amand, B. Urbaszek, M. M. Glazov, and...


[36] Naseer Muhammad, Yang Chen, Cheng Wei Qiu, and Guo Ping Wang. Optical Bound States in


Figure 1: Fabrication procedure for WS$_2$ nano-antennas. (a) Representation of a top view of a single layer of WS$_2$ found at the top of a hexagonal nano-antenna at the position of the vertex. The zigzag axis defines the edges of the structure due to its higher stability as shown by the two bonds on outlying sulfur atoms when compared to the armchair axis with its single bond for outlying sulfur atoms. (b) Fabrication steps and their order following the black outline arrows. The first step includes spinning of resist onto a WS$_2$ flake. The second step is patterning and development after electron beam lithography into a circular or square geometry. The final step is reactive ion etching using either a more physical or chemical etching recipe. The height (h) is defined by the thickness of the original flake. The radius of the structure is defined as the distance from the center of the structure to an outside vertex for hexagonal and square geometries. (c) AFM and SEM images of fabricated nano-antennas. The left column shows 3D representations of AFM scans of circular, hexagonal and square nano-antennas in the top, middle and bottom row respectively. Scale bars in AFM scans = 200 nm. The right column shows SEM images of similar structures taken at a 60° tilt of the sample. Scale bars in SEM images = 100 nm.
Figure 2: Dark field spectroscopy and second harmonic generation enhancement of hexagonal dimer nano-antennas. (a) Left panel: Schematic illustration of a hexagonal dimer nano-antenna. Right panel: SEM image of the top view of a fabricated hexagonal dimer nano-antenna. (b) Dark field spectroscopy experiments (blue, purple, yellow lines) compared to scattering cross section simulations (black dashed lines) of dimer nano-antennas with different radii ($r = 165$ nm, $r = 185$ nm, $r = 200$ nm) and a height of 60 nm. Dashed red lines correspond to simulated electric energy confined in the nano-antenna at mid-height. The anapole mode is highlighted with a vertical green dashed line. (c) Left (Right) panel: Top view of the electric (magnetic) field intensity in the plane positioned at mid-height of the dimer nano-antenna ($r = 200$ nm, $h = 60$ nm, $g = 70$ nm) height at the anapole mode (800 nm) under illumination with a polarization parallel to the double white arrow in the top left of the image. Grey field lines represent the electric charge currents inside and surrounding the structure, highlighting the characteristic anapole mode pattern. Dashed white outlines represent the physical edges of the structure. Scale bars = 100 nm. (d) Spectrum of second harmonic generation normalized to the excited area from a dimer nano-antenna (yellow) ($r = 205$ nm, $h = 60$ nm, $g = 130$ nm), a monomer nano-antenna (red) ($r = 215$ nm, $h = 50$ nm) and a bulk crystal (purple) ($h = 60$ nm). Excitation polarized perpendicular to the dimer axis as shown by the double black arrow in the inset. Dashed curves represent a Gaussian fit to the data. (e) Normalized, integrated polarization resolved second harmonic signal emitted from the dimer (yellow) ($r = 200$ nm, $h = 60$ nm, $g = 130$ nm) and monomer (red) ($r = 240$ nm, $h = 50$ nm) nano-antennas as well as the bulk crystal (purple) ($h = 60$ nm). The linear polarization of the excitation was set at an angle defined with respect to the dimer axis explained by the inset. Dashed lines represent the scaled FDTD simulated $||W_S^2||^2$ polarization dependence for dimer (yellow) and monomer (red) nano-antennas with a similar geometry.
Figure 3: AFM repositioning of dimer nano-antennas. (a) Schematic illustration of the scanning technique used in contact mode AFM to translate and rotate single nano-pillars of the dimer nano-antenna. (b) AFM scan of a dimer structure ($r = 140$ nm, $h = 170$ nm, gap = 105 nm) before and after manipulation. The dimer gap is reduced to 15 nm and one pillar is rotated by $8^\circ$ in order to position inside vertices closer to each other. (c) Dark field scattering spectra of the dimer-nano-antenna for excitation parallel to the dimer axis (as shown in inset) before and after repositioning compared to a simulated scattering cross section with gaps of 105 nm and 15 nm.
Figure 4: Simulations of the electric field hotspots and Purcell enhancement for single photon emission. (a) Top-view and side-view spatial distributions of the electric field intensity in and surrounding optimized designs of each geometry of WS$_2$ dimer nano-antennas at 10 nm separation gap. Circular design: $r = 225$ nm, $h = 200$ nm, wavelength = 751.5. Hexagonal design: $r = 240$ nm, $h = 200$ nm, radius of curvature of vertices = 22 nm, wavelength = 749.5. Square design: $r = 260$ nm, $h = 150$ nm, radius of curvature of vertices = 10 nm, wavelength = 697.5. Hotspots of electric field confinement form at inner and outer edges of the dimer. Incident plane wave polarization (X-pol) is parallel to the double white arrow in the top left corner of the panels. Axes indicate cross-section with (x,y) indicating a surface 0.5 nm above the top of the dimer and (x,z) indicating a vertical cut through the dimer axis. Dashed white outlines represent the physical edges of the structures. Scale bars = 100 nm. (b) Purcell enhancement for a dipole placed at different positions with polarization parallel to the dimer axis, 0.5 nm above the top surface of the structures. Solid dots and lines indicate dimers with a gap of 10 nm and dashed lines indicate dimers with a gap of 50 nm. Placement positions of the dipole above the dimer are shown as solid white lines in (a). (c) Illustration of the change in dimer gap used for the simulations in (d) and (e). (d),(e) Gap dependent maximum electric field intensity and Purcell factor within the hotspot of the optimized dimer designs for each geometry at the previously used wavelengths. (f) Top-view SEM images of hexagonal dimer nano-antennas demonstrating the ability to utilize the crystal symmetry to fabricate structures with a rotation ($\theta$) relative to the dimer axis. Red circles indicate position of electric field hotspot or dipole source for Purcell enhancement in (c) and (f) (g),(h) Rotation angle dependent maximum electric field intensity and Purcell factor within the hotspot of the optimized dimer designs for the square and hexagonal geometries at the previously used wavelengths.
Figure 5: Optical trapping simulations of nano-particles using WS$_2$ hexagonal nano-antennas. (a) Schematic illustration of optical trapping of a nano-particle in water through the use of WS$_2$ hexagonal dimer nano-antenna hotspots. (b),(c) Comparison of the optical force for a spherical nano-particle ($r = 5$ nm) placed in the middle of the dimer nano-antenna ($r = 240$ nm, $h = 200$ nm) gap, along the $z$-axis for gaps of 10 nm and 15 nm. The trapping force is calculated at the wavelength of its maximum value for a QD (763 nm) and a PB (755 nm). Insets illustrate the positioning of the respective nano-particle with the zero position at the top surface of the nano-antenna. (d) Maximum electric force applied to a QD (purple line) and a PB (yellow line) at the top surface of a dimer nano-antenna ($r = 240$ nm, $h = 200$ nm) with a varying gap separation. (e),(f) Attractive force distribution for a nano-particle in a plane 5 nm from the top surface of a dimer nano-antenna ($r = 240$ nm, $h = 200$ nm, $g = 10$ nm) centered at the dimer nano-antenna gap. The trapping force is calculated at the wavelength of its maximum value for a QD (763 nm) and a PB (755 nm). Double white arrow in upper left portion of figure identifies the pump polarization along the dimer axis (X-pol). Dashed white lines identify the physical edges of the structure. Inset schematics highlight the position of the plane over which the optical force is simulated. Maximum force values coincide with the electric field hotspots. Input pump power density used for all simulations is 10 mW/µm$^2$.
Supplementary Note 1: Photonic resonances of monomer nano-antennas

As displayed in Fig. S1(a)-(c), we measured dark field spectra for hexagonal monomer nano-antennas of three different heights (170 nm, 60 nm and 25 nm) over a range of radii (100 - 370 nm) and subsequently simulated the fabricated geometries which, as shown in Fig. S1(d)-(f), exhibit close agreement to the experimental data. Examples of individual experimentally measured and simulated spectra for hexagonal nano-antennas of different heights are shown in Fig. S1(g)-(i). We identified an electric dipole resonance with small contributions from higher order modes (labeled ED) [1]. More complex resonances were also present in the fabricated monomer nano-antennas such as the anapole and higher order anapole mode (HOAM) (cyan), seen as minima in dark field spectra shown in the middle and right column of Fig. S1 [2].
Figure S1: Comparison of dark field spectroscopy to scattering cross section simulations for monomer nano-antennas. (a)-(c) Dark field spectroscopy results for nano-antennas with heights of 170 nm, 60 nm and 25 nm respectively. Identified resonances include a broadened electric dipole (ED) resonance as well as anapole and higher order anapole modes (HOAM). (d)-(f) Scattering cross section simulations for nano-antennas with heights of 170 nm, 60 nm and 25 nm respectively. Simulations confirm the identification of ED, anapole and HOAM resonances. (g)-(i) A comparison between dark field spectroscopy and scattering cross section simulations for individual radii (150 nm, 200 nm, 290 nm) as defined by a horizontal dashed white line in upper panels for the three heights (170 nm, 60 nm, 25 nm).

It is clear from the data and simulation results for all heights in Fig. S1, as expected from Mie theory, that an increase in resonator radius leads to the scattering of longer wavelengths of light, thereby red-shifting the modes. The height of the nano-antennas also plays an important role in the resonance wavelength as shown in the comparisons of experiment to simulation (Fig. S1(g)-(i)) for a single radius at each height corresponding to the dashed white lines in the upper panels. Here it can be observed that a decrease in height (from 170 nm to 25 nm) blue-shifts the resonances in the nano-antenna despite the increase in radius (150 nm to 290 nm) when moving from Fig. S1(g) to (i).
Supplementary Note 2: Scattering comparison of nano-antenna geometry

The definition of the radius leaves the possibility of a change in volume when there is a change in geometry even if the radius remains the same. Since the modes inside our structures are Mie resonances, they are heavily dependent on the geometry and the volume of the high refractive index nano-antenna [3]. As the volume increases so does the wavelength of the resonance because its fundamental mode must now fit inside a larger geometry.

In figure S2 we have compared the simulated scattering cross section expected from the three different WS$_2$ monomer nano-antenna geometries we were able to fabricate. These calculations are done in vacuum in order to allow us to identify modes which will broaden with the addition of a substrate. We set the same height (150 nm) and range of radii (80-250 nm) for the different geometries. We are able to identify a magnetic dipole resonance which we denote as MD, an electric dipole resonance denoted as ED and the more complex anapole and higher order anapole mode (HOAM). We also notice that the resonances blue-shift when moving from circular to hexagonal to square nano-antennas with the same radius as expected from the geometrical argument.

![Figure S2: Scattering cross section comparison of circular, hexagonal and square geometries](image)

Figure S2: Scattering cross section comparison of circular, hexagonal and square geometries. The height of all structures was kept at 150 nm with a varying radius (80-250 nm) in order to show the blue-shift of the resonances with decreasing volume of the antenna for the hexagonal and square geometries. Identified resonances include a magnetic dipole resonance (MD), an electric dipole resonance (ED), an anapole mode and a higher order anapole mode (HOAM).
Supplementary Note 3: Hybridization of monomer nano-antenna resonances in dimer nano-antennas

When two monomer nano-antennas are separated by a distance smaller or on the order of the wavelength of the individual resonances of structures, these modes begin to hybridize and therefore split energetically. This allows the formation of two new cross-polarized modes (X-pol and Y-pol) which are now photonic resonances of the new dimer nano-antenna.

As shown in figure S3, we can easily compare the simulated scattering cross section of two nano-pillars (r = 250 nm, h = 150 nm) on a SiO$_2$ substrate separated by a 2 µm gap to the scattering cross section of two completely isolated monomer nano-antennas. Here we simulate an excitation plane wave polarized along the dimer axis (X-pol) as shown by the black double arrow in the top right of the figure as well as perpendicular to this (Y-pol). For a separation of 2 µm, we do not see a splitting into perpendicularly polarized modes and a good agreement with the scattering cross section of two individual monomer nano-antennas. However, as we reduce the separation distance of the dimer to 500 nm and subsequently to 50 nm we see a splitting at the anapole mode minimum (750-770 nm) and at the dipole resonance (670-700 nm) for the two cross polarized modes clearly showing the hybridization of the individual resonances of the monomer nano-antennas placed in close proximity with relation to the wavelength of the resonances.

Figure S3: Hybridization of individual resonances in dipole nano-antennas. Simulated scattering cross sections for dimers with three different gap distances with excitation polarization along the dimer axis (yellow) and perpendicular to it (red). At large gap distances such as 2 µm one can compare the resonances for both incident polarizations to two isolated monomer nano-antennas. At small gap distances, the modes split along the different polarization directions yielding two cross-polarized anapole and dipole resonances. Radius = 250 nm. Height = 150 nm. Spectra are vertically offset for better visualization of the results.
Supplementary Note 4: Cross-polarized dark field spectra of dimer nano-antenna anapole modes

The dark field scattering spectrum surrounding the dimer anapole mode for the cross-polarized resonances of nano-antennas with a height of 60 nm, a gap of 130 nm and radii of 165, 185 and 200 nm is shown in Fig. S4. The energy splitting for the two excitation polarizations is clear with the black curves representing excitation polarization along the dimer axis and the colored curves (purple, red and yellow) representing polarization perpendicular to the dimer axis. The splitting is less evident in the scattering spectra of the larger radius dimers due to an unrelated low energy peak which obscures the anapole mode position.

Figure S4: Dark field scattering spectra for excitation polarization along the dimer axis and perpendicular to it. (a)-(c) The black curves correspond to the excitation polarization along the dimer axis and the three colored curves (purple, red and yellow) correspond to an excitation perpendicular to the dimer axis for the three different radii of dimer nano-antennas (165, 185, 200 nm), a height of 60 nm and a gap of 130 nm. Dashed lines represent the anapole mode spectral positions.
Supplementary Note 5: Dark field spectra of dimer nano-antennas for a range of radii

The dark field scattering spectra under unpolarized excitation shown in Fig. 2 of the main text are part of a larger set shown here in Fig. S5. The heights of the nano-antennas are all 60 nm with the radii ranging from 168 nm to 216 nm. The anapole mode seen as the major feature of these spectra red-shifts from 730 nm to 843 nm. This study provides evidence that the resonances of the dimer nano-antennas are just as tunable as for the monomers with a change in radius.

![Figure S5](image_url)

**Figure S5:** Dark field scattering spectra for unpolarized excitation compared to scattering cross section simulations. (a) Offset dark field spectra compared to simulations for a range of radii (168 nm to 184 nm) with a height of 60 nm. (b) Same as (a) for a range of radii (198 nm to 216 nm) with the same height. The solid green line highlights the position of the anapole mode in these structures.
Supplementary Note 6: Comparison of monomer and dimer anapole modes

Similar to dipole or quadrupole resonances, the anapole modes in monomers will hybridize when a dimer nano-antenna is formed. This hybridization will lead to confinement of a portion of the electric field intensity outside the nano-antenna geometry. Figs. S6(a) and (b) show the induced electric field intensity of the anapole mode in and surrounding a monomer (r = 200, h = 60 nm) and dimer (r = 200 nm, h = 60 nm, g = 70 nm) nano-antenna respectively at the midpoint of their height (30 nm) for an excitation polarization perpendicular to the dimer axis. However, it is interesting to note that electric field intensity anti-nodes in the dimer nano-antenna at this small gap separation are higher than those for the monomer signifying more tightly confined light.

Second harmonic generation is a second order process which, to a dipole approximation, is a surface phenomenon which scales with the electric energy at the excitation wavelength squared, $|W_E|^2$ [4]. Therefore, we calculated the electric energy confined to the inside of the nano-pillars at the surface described for Figs. S6(a) and (b) using the following definition [4]:

$$W_{E}^{(S)} = \frac{n^2}{2} \int \int |E(r, \lambda)|^2 dS$$

(1)

where $n$ is the refractive index and $|E(r, \lambda)|^2$ is the electric field intensity. The integration was carried out over the inside surface of the nano-antennas for a range of wavelengths. Figs. S6(c) and (d) display the confined electric energy (red dashed lines) inside the monomer and the dimer nano-antenna respectively with a simulated scattering cross section (black solid lines) for each as a reference to the anapole mode. The scattering cross sections show a deeper minimum for the dimer anapole mode and an increased maximum confined electric energy (by a factor of 1.9) for the dimer nano-antenna when compared to the monomer. Two uncoupled monomers would yield a slightly higher electric energy than a dimer nano-antenna leading to higher SHG enhancement in the monomer when the electric energy is squared [4]. The comparable result of Fig. 2(d) in the main text with a slightly higher signal for the dimer nano-antenna can be attributed to the exact choice of excitation wavelength as well as fabrication error.

Figure S6: Comparison of near-field electric field intensities and confined electric energies for the monomer and dimer anapole modes. (a),(b) Electric field intensity spatial distributions for a cross-section at mid-height (30 nm) for a monomer (r = 200 nm, h = 60 nm) and dimer (r = 200 nm, h = 60 nm, g = 70 nm) nano-antenna respectively at the anapole mode wavelength. The the double arrows in the top left of both (a) and (b) indicate the polarization direction of the excitation. The gray lines represent the electric field in and surrounding the nano-antenna at this cross section. Dashed white outlines represent the physical edges of the structure. Scale bars = 100 nm. (c),(d) Simulated scattering cross section and confined electric energy inside the mid-height cross section of the monomer and dimer nano-antennas respectively. The scattering and electric energy spectra are normalized to the maximum of the dimer response for comparison. The vertical dashed, green line indicates the position of the anapole mode.
Supplementary Note 7: Further Atomic force microscopy (AFM) repositioning experiments

In order to provide evidence for the reproducibility of the AFM dimer repositioning method, we show before and after scans (Fig. S7) of two more nano-antennas which have been repositioned. In Fig. S7(a) we achieve a rotation of $17^\circ$ as well as a reduction of the dimer gap from 110 nm to 10 nm, which is the smallest achieved in our experiments, for a dimer with a radius of 163 nm and a height of 167 nm. In Fig. S7(b) we show a rotation of $57^\circ$ and a gap reduction from 127 nm to 27 nm for a dimer with a radius of 140 nm and a height of 168 nm.

![Figure S7: Additional exemplary AFM scans before and after repositioning manipulations. (a) AFM scans of dimer nano-antenna before and after repositioning with a radius of 163 nm, a height of 167 nm, a reduction in gap from 110 nm to 10 nm and a rotation of $17^\circ$. (b) AFM scans of another dimer nano-antenna before and after repositioning with a radius of 140 nm, a height of 168 nm, a reduction in gap from 127 nm to 27 nm and a rotation of $57^\circ$.](image-url)
Supplementary Note 8: Radius of curvature measurement

In order to provide simulations of the electric field and Purcell enhancement for realistic fabricated structures, we measured the radius of curvature of vertices of many of our fabricated structures with atomic force microscopy and used recorded values in further simulations including those seen in Fig. 4 of the main text. Since many of the square and hexagonal structures exhibited a radius of curvature below or on the order of the maximum resolution of our AFM measurements, we used a geometric approach described below to reliably measure the radius of curvature.

In Figs. S8(a) and (b), we have shown an example of the square \( (r = 265 \text{ nm}, h = 84 \text{ nm}, \text{gap} = 220 \text{ nm}) \) and hexagonal \( (r = 240 \text{ nm}, h = 135 \text{ nm}, \text{gap} = 90 \text{ nm}) \) dimer nano-antenna AFM scans from which we extracted values of the radius of curvature of the vertices. For both geometries, we collected data from the top surface of the nano-antennas where the bottom of the AFM tip made contact with the structure to provide the highest resolution possible. The extracted value from the AFM scans denoted as \( x \) in Figs. S8(c) and (d) is the shortest distance between two edges which are at 90° or 120° relative to each other for the square and hexagonal geometries respectively. This can be thought of as the base of a triangle formed by two radii of curvature which perpendicularly intersect the edges of the respective structure and the angle between them can easily be calculated to be 90° and 60° for the square and hexagonal geometries respectively. The radius denoted as \( r \) in the figure can then be computed using the Pythagorean theorem.

![AFM scans showing method of extracting vertex radius of curvature](image)

Figure S8: AFM scans showing method of extracting vertex radius of curvature. (a),(b) AFM scans of exemplary square \( (r = 265 \text{ nm}, h = 84 \text{ nm}, \text{gap} = 220 \text{ nm}) \) and hexagonal \( (r = 240 \text{ nm}, h = 135 \text{ nm}, \text{gap} = 90 \text{ nm}) \) dimer nano-antennas. (c),(d) Portions of the previous AFM scans shown as dashed red squares in (a) and (b). These are overlapped with solid red lines at 90° and 120° to each other showing the top edges of the structures with an inscribed solid circle which is used to extract the radius (denoted \( r \)) of curvature of the vertex. Distance measured from the AFM scan is denoted by \( x \) which is the shortest distance between the top two edges of the structure.
References


